

Revision 0.94

SINGLE FREQUENCY LASER DIODES Distributed Feedback Laser



General Product Information

Product	Application
Tunable 760 nm DFB Laser	Spectroscopy
with hermetic 14 Pin Butterfly Housing (RoHS compliant)	Metrology
including Monitor Diode, Thermoelectric Cooler and Thermistor	Oxygen Detection
with integrated Beam Collimation	



Absolute Maximum Ratings

Parameter	Symbol	Unit	min	typ	max
Storage Temperature	T _S	°C	-40		85
Operational Temperature at Case	T_{C}	°C	-40		85
Operational Temperature at Laser Chip	T_LD	°C	10		50
Forward Current	I _F	mA			130
Reverse Voltage	V_R	V			2
Output Power	P_{opt}	mW			50
TEC Current	I_{TEC}	Α			1.1
TEC Voltage	V_{TEC}	V			2.8

Measurement Conditions / Comments

Stress in excess of one of the Absolute Maximum Ratings may damage the laser. Please note that a damaging optical power level may occur although the maximum current is not reached. These are stress ratings only, and functional operation at these or any other conditions beyond those indicated under Recommended Operational Conditions is not implied.

Recommended Operational Conditions

Parameter	Symbol	Unit	min	typ	max
Operational Temperature at Case	T_{case}	°C	-20		65
Operational Temperature at Laser Chip	T_LD	°C	10		35
Forward Current	I _F	mA			120
Output Power	P_{opt}	mW	10		40

Measurement Conditions / Comments
measured by integrated thermistor

Characteristics at T_{LD} = 25° C at BOL

Parameter	Symbol	Unit	min	typ	max
Center Wavelength	λ_{C}	nm	759.9	760.9	761.9
Target Wavelength	λ_{T}	nm		760.9	
Linewidth (FWHM)	$\Delta\lambda$	MHz		2	
Mode-hop free Tuning Range	$\Delta \lambda_{\text{tune}}$	pm	40		
Sidemode Supression Ratio	SMSR	dB	30	50	

Measurement Conditions / Comments
reached within T_{LD} = 10° and 35° C at 40 mW
$P_{opt} = 40 \text{ mW}$
at target wawevelength
$P_{opt} = 40 \text{ mW}$



Revision 0.94

SINGLE FREQUENCY LASER DIODES Distributed Feedback Laser



Characteristics at T _{LD} = 25° C	at BOL				cont'd
Parameter	Symbol	Unit	min	typ	max
Temperature Coefficient of Wavelength	dλ / dT	nm / K		0.06	
Current Coefficient of Wavelength	dλ / dl	nm / mA		0.002	
Laser Current @ P _{opt} = 40 mW	I_{LD}	mA			120
Slope Efficiency	η	W/A	0.6	0.8	1.3
Threshold Current	I _{th}	mA			70
Divergence parallel (FWHM)	$\Theta_{ }$	0		0.1	
Divergence perpendicular (FWHM)	Θ_{\perp}	0		0.1	
Beam Diameter horizontal	d	mm		1.0	1.2
Beam Diameter vertical	d_{\perp}	mm		0.8	1.2
Degree of Polarization	DOP	%		90	

Massurement Conditions / Comments
Measurement Conditions / Comments
parallel to the base plate of the housing (see p. 3)
perpendicular to base plate of the housing (see p. 3)
parallel to the base plate of the housing (see p. 3)
perpendicular to base plate of the housing (see p. 3)
$P_{\text{opt}} = 40$ mW; E field perpendicular to base plate

Monitor Diode					
Parameter	Symbol	Unit	min	typ	max
Monitor Detector Responsivity	I _{mon} / P _{opt}	μA/mW	3		60

$U_R = 5 \text{ V}$	Meası	urement Conditions / Comments
	$U_R =$	5 V

Symbol	Unit	min	typ	max
I _{TEC}	А		0.4	
U_TEC	V		1.3	
P _{loss}	W		0.4	
ΔΤ	K			50
	I _{TEC}	I _{TEC} A V	I _{TEC} A V	I _{TEC} A 0.4 U _{TEC} V 1.3

P _{opt} =	= 40 mW	ΔT =	20 k	(
P _{opt} =	40 mW	ΔT =	20 k	(
P _{opt} =	= 40 mW	ΔT =	20 k	(
P _{opt} =	40 mW	ΔT =	Tca	se - T	LD		

Thermistor (Standard NTC Type)							
Parameter	Symbol	Unit	min	typ	max		
Resistance	R	kΩ		10			
Beta Coefficient	β			3892			
Steinhart & Hart Coefficient A	А		1.1293 x 10 ⁻³				
Steinhart & Hart Coefficient B	В		2.3410 x 10 ⁻⁴				
Steinhart & Hart Coefficient C	C			8.7755 x 10	-8		

Measurement Conditions / Comments					
T _{LD} = 25° C					
$R_1 / R_2 = e^{\beta (1/T_1 - 1/T_2)} $ at $T_{LD} =$	0° 50° C				
$1/T = A + B(\ln R) + C(\ln R)^3$					
T: temperature in Kelvin					
R: resistance at T in Ohm					



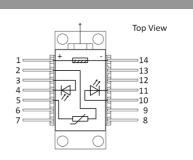
Revision 0.94

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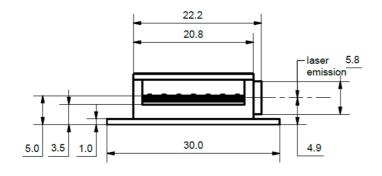


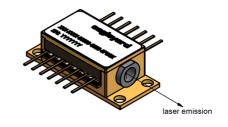
Pin Assignment

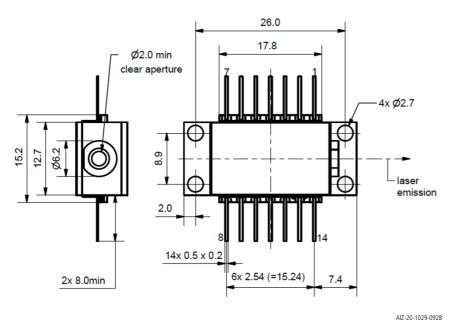
2Thermistor13Case3Photodiode (Anode)12not connected4Photodiode (Cathode)11Laser Diode (Cathode)5Thermistor10Laser Diode (Anode)6not connected9not connected	1	Thermoelectric Cooler (+)	14	Thermoelectric Cooler (-)
4 Photodiode (Cathode) 11 Laser Diode (Cathode) 5 Thermistor 10 Laser Diode (Anode)	2	Thermistor	13	Case
5 Thermistor 10 Laser Diode (Anode)	3	Photodiode (Anode)	12	not connected
	4	Photodiode (Cathode)	11	Laser Diode (Cathode)
6 not connected 9 not connected	5	Thermistor	10	Laser Diode (Anode)
	6	not connected	9	not connected
7 not connected 8 not connected	7	not connected	8	not connected



Package Drawings







Caution. Excessive mechanical stress on the package can lead to a damage of the laser.

See <u>instruction manual</u> on www.eagleyard.com



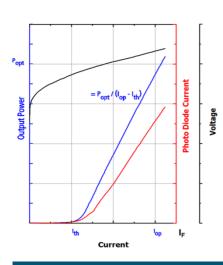
Revision 0.94

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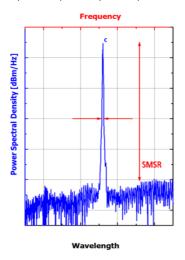


Typical Measurement Results

Output Power vs. Current



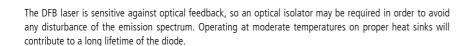
Spectra at Specified Optical Output Power



Performance figures, data and any illustrative material provided in this specification are typical and must be specifically confirmed in writing by eagleyard Photonics before they become applicable to any particular order or contract. In accordance with the eagleyard Photonics policy of continuous improvement specifications may change without notice.

Unpacking, Installation and Laser Safety

Unpacking the laser diodes should only be done at electrostatic safe workstations (EPA). Though protection against electro static discharge (ESD) is implemented in the laser package, charges may occur at surfaces. Please store this product in its original package at a dry, clean place until final use. During device installation, ESD protection has to be maintained.



Avoid direct and/or indirect exposure to the free running beam. Collimating and focussing the free running beam with optics as common in optical instruments will increase threat to the human eye.

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